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Pages 1 to 19

**TRANSISTORS, MATCHED DUAL, PNP,
BASED ON TYPES 2N3810 AND 2N3811
ESA/SCC Detail Specification No. 5207/005**



**space components
coordination group**

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		SCCG Chairman	ESA Director General or his Deputy
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**DOCUMENTATION CHANGE NOTICE**

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		This Issue supersedes Issue 5 and incorporates all modifications defined in Revision 'A' to Issue 5 and the changes agreed by the following DCRs:-		
		Cover Page		None
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		Para. 1.1	: Existing text deleted and new text added	221491
		Para. 2	: Item (c) deleted	221491
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			: "(a)" added to existing Figure 2 entries	221491
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			: For h _{FE2} , Max. Limit amended for Variants 01, 02, 05	221491
		Table 2 a.c.	: No. 15, Variants 07 and 08 added to Test Conditions	221491
			: No. 16, Variants 07 and 08 added to Test Conditions	221491
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		Table 5	: Main Title deleted	221491
			: First Subtitle amended	221491
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			: Both Subtitles amended	221491
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		Table 6	: No. 6, Variants 07 and 08 added to Test Conditions	221491
			: Second No. 10, Renumbered as 10(a)	221491


 SCC	ESA/SCC Detail Specification No. 5207/005		PAGE 3 ISSUE 6
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TABLE OF CONTENTS

		<u>Page</u>
1.	<u>GENERAL</u>	5
1.1	Scope	5
1.2	Component Type Variants	5
1.3	Maximum Ratings	5
1.4	Parameter Derating Information	5
1.5	Physical Dimensions	5
1.6	Functional Diagram	5
1.7	High Temperature Test Precautions	5
2.	<u>APPLICABLE DOCUMENTS</u>	5
3.	<u>TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS</u>	5
4.	<u>REQUIREMENTS</u>	10
4.1	General	10
4.2	Deviations from Generic Specification	10
4.2.1	Deviations from Special In-process Controls	10
4.2.2	Deviations from Final Production Tests	10
4.2.3	Deviations from Burn-in and Electrical Measurements	10
4.2.4	Deviations from Qualification Tests	10
4.2.5	Deviations from Lot Acceptance Tests	10
4.3	Mechanical Requirements	10
4.3.1	Dimension Check	10
4.3.2	Weight	10
4.3.3	Terminal Strength	10
4.4	Materials and Finishes	11
4.4.1	Case	11
4.4.2	Lead Material and Finish	11
4.5	Marking	11
4.5.1	General	11
4.5.2	Lead Identification	11
4.5.3	The SCC Component Number	11
4.5.4	Traceability Information	11
4.6	Electrical Measurements	12
4.6.1	Electrical Measurements at Room Temperature	12
4.6.2	Electrical Measurements at High and Low Temperatures	12
4.6.3	Circuits for Electrical Measurements	12
4.7	Burn-in Tests	12
4.7.1	Parameter Drift Values	12
4.7.2	Conditions for High Temperature Reverse Bias Burn-in	12
4.7.3	Conditions for Power Burn-in	12
4.7.4	Electrical Circuits for High Temperature Reverse Bias Burn-in	12
4.7.5	Electrical Circuits for Power Burn-in	12
4.8	Environmental and Endurance Tests	18
4.8.1	Electrical Measurements on Completion of Environmental Tests	18
4.8.2	Electrical Measurements at Intermediate Points and on Completion of Endurance Tests	18
4.8.3	Conditions for Operating Life Tests	18
4.8.4	Electrical Circuits for Operating Life Tests	18
4.8.5	Conditions for High Temperature Storage Test	18

**TABLES**



	<u>Page</u>
1(a) Type Variants	6
1(b) Maximum Ratings	6
2 Electrical Measurements at Room Temperature - d.c. Parameters	13
Electrical Measurements at Room Temperature - a.c. Parameters	15
3 Electrical Measurements at High and Low Temperatures	16
4 Parameter Drift Values	16
5(a) Conditions for High Temperature Reverse Bias Burn-in	17
5(b) Conditions for Power Burn-in and Operating Life Tests	17
6 Electrical Measurements at Intermediate Points and on Completion of Endurance Testing	19

FIGURES

1 Parameter Derating Information	7
2 Physical Dimensions	8
3 Functional Diagram	9
4 Circuits for Electrical Measurements	16
5(a) Electrical Circuit for High Temperature Reverse Bias Burn-in	17
5(b) Electrical Circuit for Power Burn-in and Operating Life Tests	17

APPENDICES (Applicable to specific Manufacturers only)

None.

 	<p style="text-align: center;">ESA/SCC Detail Specification No. 5207/005</p>	<p>PAGE 5 ISSUE 6</p>
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1. **GENERAL**

1.1 **SCOPE**

This specification details the ratings, physical and electrical characteristics, test and inspection data for a Transistor, Matched Dual, PNP, based on Types 2N3810 and 2N3811. It shall be read in conjunction with ESA/SCC Generic Specification No. 5000, the requirements of which are supplemented herein.

1.2 **COMPONENT TYPE VARIANTS**

Variants of the basic type transistors specified herein, which are also covered by this specification are given in Table 1(a).

1.3 **MAXIMUM RATINGS**

The maximum ratings, which shall not be exceeded at any time during use or storage, applicable to the transistors specified herein are scheduled in Table 1(b).

1.4 **PARAMETER DERATING INFORMATION**

The derating information applicable to the transistors specified herein is shown in Figure 1.

1.5 **PHYSICAL DIMENSIONS**

The physical dimensions of the transistors specified herein are shown in Figure 2.

1.6 **FUNCTIONAL DIAGRAM**

The functional diagram showing lead identification, of the transistors specified herein, is shown in Figure 3.

1.7 **HIGH TEMPERATURE TEST PRECAUTIONS**

For tin-lead plated or solder-dipped lead finish, all tests to be performed at a temperature that exceeds +125°C shall be carried out in a 100% inert atmosphere.

2. **APPLICABLE DOCUMENTS**

The following documents form part of this specification and shall be read in conjunction with it:-

- (a) ESA/SCC Generic Specification No. 5000 for Discrete Semiconductor Components.
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices.

3. **TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS**

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESA/SCC Basic Specification No. 21300 shall apply. In addition, the following symbols are used:-

- $|V_{BE1} - V_{BE2}|$ - Absolute value of base-emitter voltage differential between the individual sections.
- $|\Delta(V_{BE1} - V_{BE2})\Delta T_{amb}|$ - Absolute value of the algebraic difference between the base-emitter voltage differentials between the individual sections at two different temperatures.
- I_{LK} - Leakage current between active devices.

**TABLE 1(a) - TYPE VARIANTS**

VARIANT	BASED ON TYPE	CASE	FIGURE	LEAD MATERIAL AND/OR FINISH
01	2N3810	TO78	2(a)	D2
02	2N3810	TO78	2(a)	D3 or D4
03	2N3811	TO78	2(a)	D2
04	2N3811	TO78	2(a)	D3 or D4
05	2N3810	TO78	2(a)	D7
06	2N3811	TO78	2(a)	D7
07	2N3810	LCCC6	2(b)	2
08	2N3811	LCCC6	2(b)	2
09	2N3810	LCCC6	2(b)	4
10	2N3811	LCCC6	2(b)	4

TABLE 1(b) - MAXIMUM RATINGS

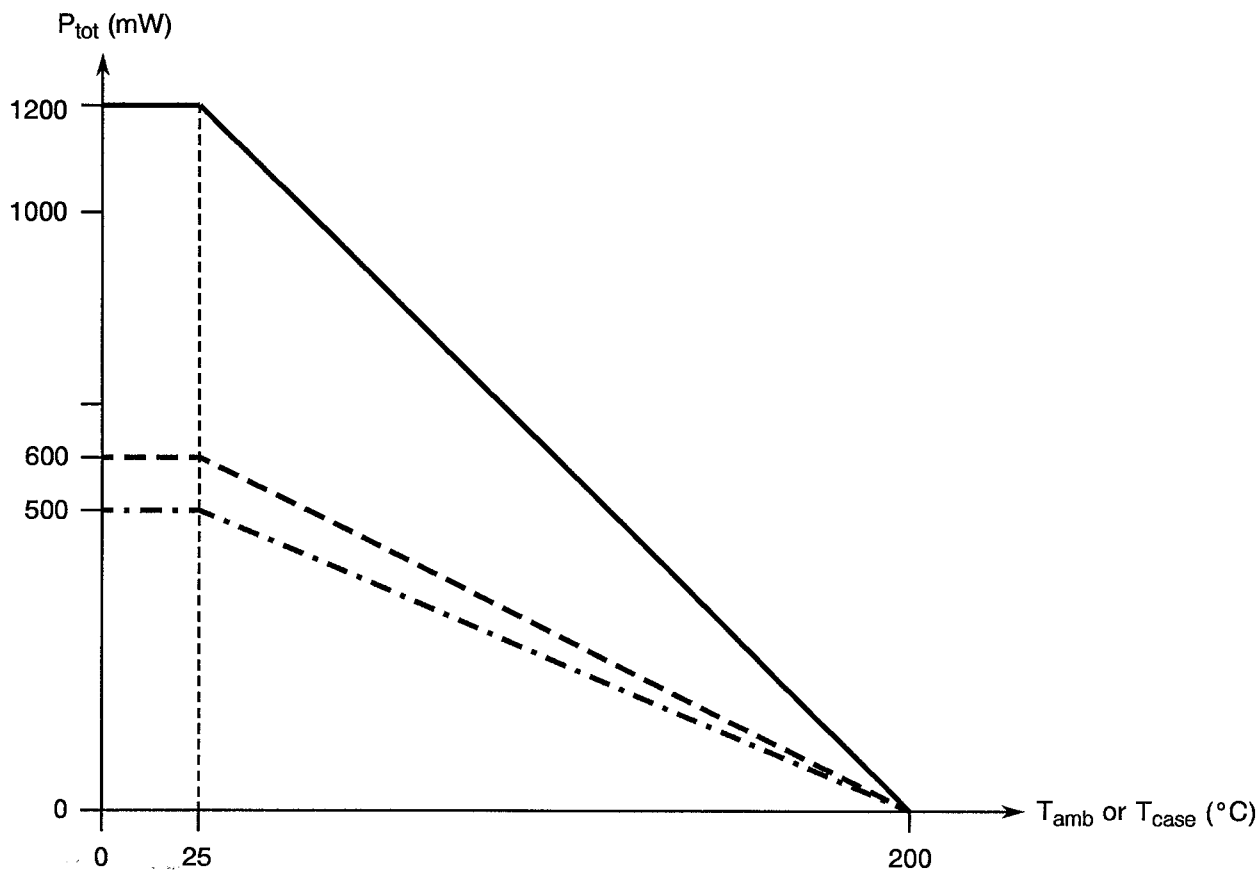
No.	CHARACTERISTICS	SYMBOL	MAXIMUM RATINGS	UNIT	REMARKS
1	Collector-Base Voltage	V_{CBO}	- 60	V	
2	Collector-Emitter Voltage	V_{CEO}	- 60	V	
3	Emitter-Base Voltage	V_{EBO}	- 5.0	V	
4	Collector Current (Continuous)	I_C	50	mA	
5	Power Dissipation 1 All Variants	P_{tot1}	0.5 (Note 1) 0.6 (Note 2)	W	$T_{amb} \leq +25^\circ C$
	Variants 07 to 10		0.6 (Notes 1 and 2) 1.2 (Notes 1 and 3)		
6	Power Dissipation 2 Variants 01 to 06	P_{tot2}	0.5 (Note 1) 0.6 (Note 2)	$^\circ C$	$T_{case} \leq +25^\circ C$
7	Operating Temperature Range	T_{op}	- 55 to + 200	$^\circ C$	T_{amb} or T_{case}
8	Storage Temperature Range	T_{stg}	- 65 to + 200	$^\circ C$	
9	Soldering Temperature Variants 01 to 06	T_{sol}	+ 260	$^\circ C$	Note 4 Note 5
	Variants 07 to 10		+ 245		

NOTES

- One section. For derating at T_{amb} or $T_{case} > +25^\circ C$, see Figure 1.
- Both sections. For derating at T_{amb} or $T_{case} > +25^\circ C$, see Figure 1.
- When mounted on a 15 x 15 x 0.6 mm substrate.
- Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body, and the same lead shall not be resoldered until 3 minutes have elapsed.
- Duration 5 seconds maximum and the same terminal shall not be resoldered until 3 minutes have elapsed.



FIGURE 1 - PARAMETER DERATING INFORMATION



Power Dissipation versus Temperature

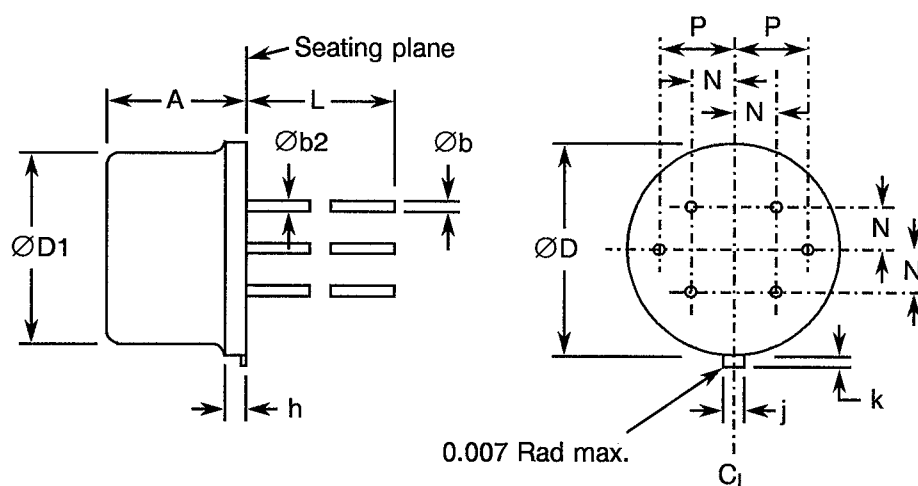
Legend

- Variants 01 to 06, T_{amb} or T_{case} one section.
- Variants 01 to 06, T_{amb} or T_{case} both sections.
- - - - - Variants 07 to 10, T_{amb} one section, when mounted on a 15 x 15 x 0.6mm ceramic substrate.
- Variants 07 to 10, T_{amb} both sections, when mounted on a 15 x 15 x 0.6 mm ceramic substrate.



FIGURE 2 - PHYSICAL DIMENSIONS

FIGURE 2(a) - VARIANTS 01 TO 06



SYMBOL	MILLIMETRES		NOTES
	MIN.	MAX.	
A	3.81	4.57	
Øb	0.41	0.53	1, 6
Øb2	0.41	0.48	2, 6
ØD	8.51	9.40	
ØD1	7.75	8.51	
h	0.23	1.04	
j	0.71	0.86	7
k	0.74	1.14	5
L	12.70	44.45	6
N	1.80 NOM.		3
P	2.54 NOM.		3

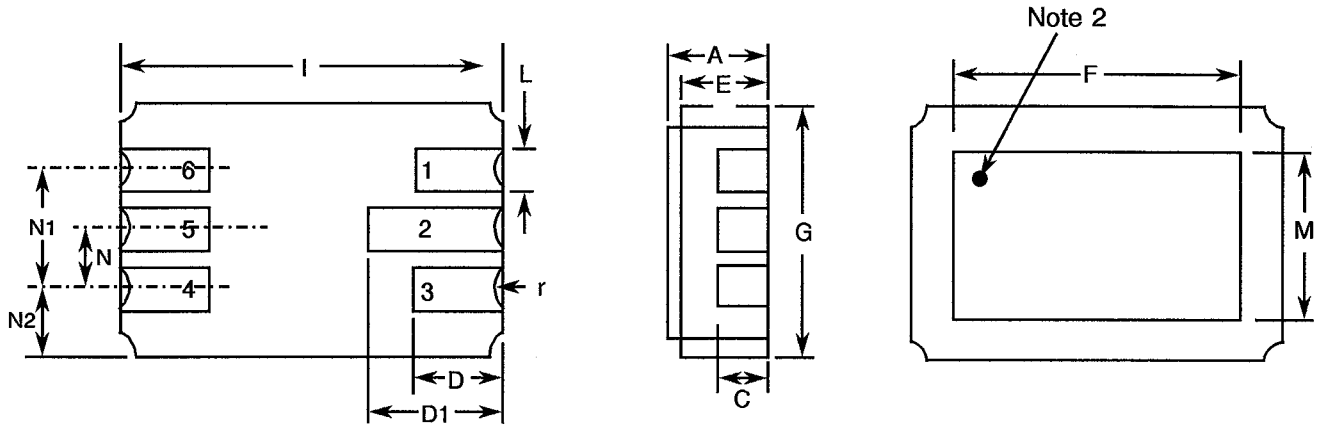
NOTES

1. Measured in the zone beyond 6.35mm from the seating plane.
2. Measured in the zone beyond 1.27mm and 6.35mm from the seating plane.
3. When measured in a gauging plane 1.37(+0.03 - 0)mm below the seating plane of the transistor, maximum diameter leads shall be within 0.18mm of their true location relative to a maximum-width-tab. Smaller diameters shall fall within the outline of the maximum diameter lead tolerance.
4. All leads electrically insulated from case and each section electrically isolated from each other.
5. Measured from the maximum diameter of the actual device.
6. All 6 leads.
7. The device may be measured by direct method or by gauge. This width to remain constant for a length of 0.55mm.



FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

FIGURE 2(b) - VARIANTS 07 TO 10



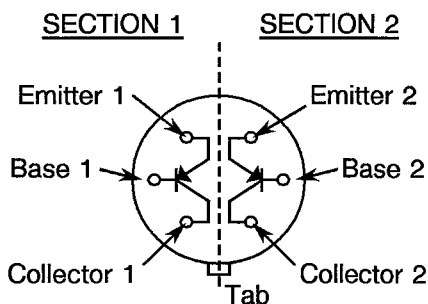
SYMBOL	MILLIMETRES		NOTES
	MIN.	MAX.	
A	1.53	1.96	1
C	0.89 TYP.		
D	1.52	1.78	
D1	2.09	2.49	
E	1.25	1.55	
F	5.76	5.91	
G	4.19	4.45	
I	6.09	6.35	
L	0.55	0.71	
M	3.86	4.01	
N	1.14	1.4	
N1	2.41	2.67	
N2	0.89 TYP.		
r	0.23 TYP.		

NOTES

- Dimensions are the same for the 6 leads.
- From topside view, pin 1 is indicated by a black ink dot.

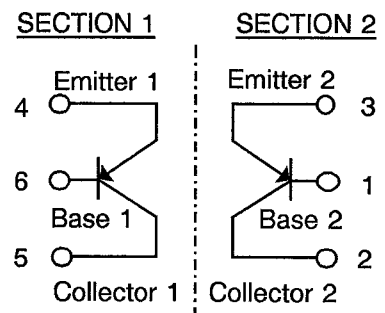
FIGURE 3 - FUNCTIONAL DIAGRAM

VARIANTS 01 TO 06



CONNECTION DIAGRAM

VARIANTS 07 TO 10



CONNECTION DIAGRAM



4. REQUIREMENTS

4.1 GENERAL

The complete requirements for procurement of the transistors specified herein are stated in this specification and ESA/SCC Generic Specification No. 5000. Deviations from the Generic Specification, applicable to this specification only, are listed in Para. 4.2.

Deviations from the applicable Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESA/SCC requirements and do not affect the components' reliability, are listed in the appendices attached to this specification.

4.2 DEVIATIONS FROM GENERIC SPECIFICATION

4.2.1 Deviations from Special In-process Controls

None.

4.2.2 Deviations from Final Production Tests (Chart II)

None.

4.2.3 Deviations from Burn-in and Electrical Measurements (Chart III)

None.

4.2.4 Deviations from Qualification Tests (Chart IV)

None.

4.2.5 Deviations from Lot Acceptance Tests (Chart V)

None.

4.3 MECHANICAL REQUIREMENTS

4.3.1 Dimension Check

The dimensions of the transistors specified herein shall be checked. They shall conform to those shown in Figure 2.

4.3.2 Weight

The maximum weight of the transistors specified herein shall be 0.95 grammes for Variants 01 to 06 and 0.2 grammes for Variants 07 to 10.

4.3.3 Terminal Strength

The requirements for terminal strength testing are specified in Section 9 of ESA/SCC Generic Specification No. 5000. For Variants 01 to 06, the test conditions shall be as follows:-

Test Condition : 'E', Lead Fatigue.

Applied Force : 2.5 ± 0.1 Newtons.

4.4 MATERIALS AND FINISHES

The materials and finishes shall be as specified herein. Where a definite material is not specified, a material which will enable the transistors specified herein to meet the performance requirements of this specification shall be used. Acceptance or approval of any constituent material does not guarantee acceptance of the finished product.

4.4.1 Case

For Variants 01 to 06, the case shall be hermetically sealed and have a metal body with hard glass seals and the lid shall be welded, brazed, preform soldered or glass frit sealed.

For Variants 07 to 10, the case shall be hermetically sealed and have a ceramic body with a kovar lid.

4.4.2 Lead Material and Finish

For Variants 01 to 06, the lead material shall be Type 'D' with either Type '2', Type '3 or 4' or Type '7' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

For Variants 07 to 08, the terminal material shall have Type '2' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

For Variants 09 to 10, the terminal material shall have Type '4' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

4.5 MARKING

4.5.1 General

The marking of all components delivered to this specification shall be in accordance with with the requirements of ESA/SCC Basic Specification No. 21700 and the following paragraphs. When the component is too small to accommodate all of the marking specified, as much as space permits shall be marked and the marking information, in full, shall accompany the component in its primary package.

The information to be marked and the order of precedence, shall be as follows:-

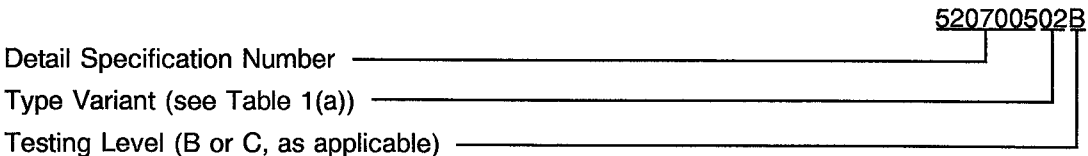
- (a) Lead Identification.
- (b) The SCC Component Number.
- (c) Traceability Information.

4.5.2 Lead Identification

Lead identification shall be as shown in Figures 2 and 3.

4.5.3 The SCC Component Number

Each component shall bear the SCC Component Number which shall be constituted and marked as follows:-



4.5.4 Traceability Information

Each component shall be marked in respect of traceability information in accordance with the requirements of ESA/SCC Basic Specification No. 21700.



4.6 ELECTRICAL MEASUREMENTS

4.6.1 Electrical Measurements at Room Temperature

The parameters to be measured at room temperature are scheduled in Table 2. Unless otherwise specified, measurements shall be performed at $T_{amb} = +22 \pm 3$ °C.

4.6.2 Electrical Measurements at High and Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3.

4.6.3 Circuits for Electrical Measurements (Figure 4)

Not applicable.

4.7 BURN-IN TESTS

4.7.1 Parameter Drift Values

The parameter drift values applicable to burn-in are specified in Table 4 of this specification. Unless otherwise stated, measurements shall be performed at $T_{amb} = +22 \pm 3$ °C. The parameter drift values (Δ) applicable to the parameters scheduled shall not be exceeded. In addition to these drift value requirements, the appropriate limit value specified for a given parameter in Table 2 shall not be exceeded.

4.7.2 Conditions for High Temperature Reverse Bias Burn-in

The requirements for high temperature reverse bias burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 5000. The conditions for high temperature reverse bias burn-in shall be as specified in Table 5(a) of this specification.

4.7.3 Conditions for Power Burn-in

The requirements for power burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 5000. The conditions for power burn-in shall be as specified in Table 5(b) of this specification.

4.7.4 Electrical Circuits for High Temperature Reverse Bias Burn-in

Circuits for used in performing the high temperature reverse bias burn-in are shown in Figure 5(a) of this specification.

4.7.5 Electrical Circuits for Power Burn-in

Circuits for use in performing the power burn-in tests are shown in Figure 5(b) of this specification.



SCC

ESA/SCC Detail Specification
No. 5207/005

Rev. 'B'

PAGE 13

ISSUE 6

TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN	MAX	
1	Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	3011	$I_C = 10\text{mA}$ $I_B = 0\text{A}$ Note 1	-60	-	V
2	Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	3001	$I_C = 10\mu\text{A}$ $I_E = 0\text{A}$	-60	-	V
3	Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	3026	$I_E = 10\mu\text{A}$ $I_C = 0\text{A}$	-5.0	-	V
4	Collector-Base Cut-off Current	I_{CBO}	3036	$V_{CB} = 50\text{V}$ $I_E = 0\text{A}$	-	-10	nA
5	Emitter-Base Cut-off Current	I_{EBO}	3061	$V_{EB} = 4.0\text{V}$ $I_C = 0\text{A}$	-	-20	nA
6	D.C. Forward Current Transfer Ratio	h_{FE1}	3076	$I_C = 10\mu\text{A}, V_{CE} = 5.0\text{V}$ Variants 01, 02, 05, 07, 09 Variants 03, 04, 06, 08, 10	100 225	- -	-
		h_{FE2}		$I_C = 100\mu\text{A}, V_{CE} = 5.0\text{V}$ Variants 01, 02, 05, 07, 09 Variants 03, 04, 06, 08, 10	150 300	450 900	
		h_{FE3}		$I_C = 500\mu\text{A}, V_{CE} = 5.0\text{V}$ Variants 01, 02, 05, 07, 09 Variants 03, 04, 06, 08, 10	150 300	450 900	
		h_{FE4}		$I_C = 1.0\text{mA}, V_{CE} = 5.0\text{V}$ Variants 01, 02, 05, 07, 09 Variants 03, 04, 06, 08, 10	150 300	450 900	
		h_{FE5}		$I_C = 10\text{mA}, V_{CE} = 5.0\text{V}$ Variants 01, 02, 05, 07, 09 Variants 03, 04, 06, 08, 10	125 250	- -	
7	Collector-Emitter Saturation Voltage	$V_{CE(SAT)1}$	3071	$I_C = 100\mu\text{A}$ $I_B = 10\mu\text{A}$ (Note 1)	-	-0.2	V
		$V_{CE(SAT)2}$		$I_C = 1.0\text{mA}$ $I_B = 100\mu\text{A}$ (Note 1)	-	-0.25	

NOTES: See Page 15.



TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN	MAX	
8	Base-Emitter Saturation Voltage	$V_{BE(SAT)1}$	3066	$I_C = 100\mu A$ $I_B = 10\mu A$ (Note 1)	-	0.7	V
		$V_{BE(SAT)2}$		$I_C = 1.0mA$ $I_B = 100\mu A$ (Note 1)	-	0.8	
9	D.C. Forward Current Transfer Ratio Comparison	$\frac{h_{FE2-1}}{h_{FE2-2}}$	3076	$I_C = 100\mu A$ $V_{CE} = 5.0V$	0.91	1.1	-
10	Base-Emitter Voltage Differential	$ V_{BE1} - V_{BE2} $	3066 Condition 'B'	$I_C = 10\mu A$ $V_{CE} = 5.0V$ (Note 2)	-	5.0	mV
				$I_C = 10mA$ $V_{CE} = 5.0V$ (Note 2)	-	5.0	
				$I_C = 100\mu A$ $V_{CE} = 5.0V$ (Note 2)	-	3.0	
11	Leakage Current between Active Devices	I_{LK}	-	$V = 50V$ to E2, B2, C2 $V = 0V$ to E1, B1, C1	-	5.0	μA

NOTES: See Page 15.

TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS (NOTE 3)	LIMITS		UNIT
					MIN	MAX	
12	Output Capacitance	C_{obo}	3236	$V_{CB} = 5.0V$ $I_E = 0A$ $100kHz < f < 1.0MHz$	-	6.0	pF
13	Input Capacitance	C_{ibo}	3240	$V_{EB} = 0.5V$ $I_C = 0A$ $100kHz < f < 1.0MHz$	-	15	pF
14	Current Gain Bandwidth Product	f_T	3076	$I_C = 1.0mA$ $V_{CE} = 5.0V$ $f = 100MHz$	80	500	MHz
15	Input Impedance	h_{ie}	3201	$I_C = 1.0mA$ $V_{CE} = 10V$ $f = 1.0kHz$ Variants 01, 02, 05, 07, 09 Variants 03, 04, 06, 08, 10	3.0 10	30 40	k Ω
16	A.C. Forward Current Transfer Ratio	h_{fe}	3206	$I_C = 1.0mA$ $V_{CE} = 10V$ $f = 1.0kHz$ Variants 01, 02, 05, 07, 09 Variants 03, 04, 06, 08, 10	150 300	600 900	
17	Noise Figure ...	N_{F1}	3246	$I_C = 200\mu A$ $V_{CE} = 5.0V$ $R_S = 2.0k\Omega$ $f = 100Hz$ Variants 01, 02, 05, 07, 09 Variants 03, 04, 06, 08, 10	-	7.0 4.0	dB
		N_{F2}		$I_C = 200\mu A$ $V_{CE} = 5.0V$ $R_S = 2.0k\Omega$ $f = 1.0kHz$ Variants 01, 02, 05, 07, 09 Variants 03, 04, 06, 08, 10	-	3.0 1.5	
		N_{F3}		$I_C = 200\mu A$ $V_{CE} = 5.0V$ $R_S = 2.0k\Omega$ $BW = 10Hz$ to $15.7kHz$ Variants 01, 02, 05, 07, 09 Variants 03, 04, 06, 08, 10	-	3.5 2.5	

NOTES

1. Pulsed measurement: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2.0\%$.
2. Any device whose measurement values exceed the specified limits shall be removed from the lot, but only count for PDA when such values exceed twice the specified limits (i.e. 10mV and 6.0mV respectively).
3. Measurements shall be performed on a sample basis, LTPD7 or less.

TABLE 3 - ELECTRICAL MEASUREMENTS AT HIGH AND LOW TEMPERATURES

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN	MAX	
4	Collector-Base Cut-off Current	I_{CBO}	3036	$T_{amb} = +150^{\circ}C$ $V_{CB} = 50V$ $I_E = 0A$	-	- 10	μA
6	D.C. Forward Current Transfer Ratio	h_{FE2}	3076	$T_{amb} = -55^{\circ}C$ $I_C = 100\mu A$, $V_{CE} = 5.0V$	60	-	-
9	D.C. Forward Current Transfer Ratio Comparison	$\frac{h_{FE2-1}}{h_{FE2-2}}$	3076	$T_{amb} = -55$ to $+125^{\circ}C$ $I_C = 100\mu A$ $V_{CE} = 5.0V$	0.85	1.18	-
10(a)	Base-Emitter Voltage Differential Change	$ \Delta(V_{BE1} - V_{BE2}) $ ΔT_{amb}	3066 Condition 'B'	$T_{amb} = -55$ to $+25^{\circ}C$ $I_C = 100\mu A$ $V_{CE} = 5.0V$	-	0.8	mV
				$T_{amb} = +25$ to $+125^{\circ}C$ $I_C = 100\mu A$ $V_{CE} = 5.0V$	-	1.0	

FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS

Not applicable.

TABLE 4 - PARAMETER DRIFT VALUES

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS (Δ)	UNIT
4	Collector-Base Cut-off Current	I_{CBO}	As per Table 2	As per Table 2	± 2.0 or (1) ± 100	nA %
6	D.C. Forward Current Transfer Ratio	h_{FE2}	As per Table 2	As per Table 2	± 15	%
7	Collector-Emitter Saturation Voltage	$V_{CE(SAT)2}$	As per Table 2	As per Table 2	± 15 or (1) ± 10	mV %

NOTES

1. Whichever is greater, referred to the initial value.

TABLE 5(a) - CONDITIONS FOR HIGH TEMPERATURE REVERSE BIAS BURN-IN

No.	CHARACTERISTICS	SYMBOL	CONDITIONS	UNIT
1	Ambient Temperature	T_{amb}	+ 150	°C
2	Collector-Base Reverse Voltage	V_{CB}	- 45 (Note 1)	V
3	Duration	t	72	Hrs

NOTES

1. After completion of test at elevated temperature, the reverse bias shall not be removed until the case has cooled to +30°C.

TABLE 5(b) - CONDITIONS FOR POWER BURN-IN AND OPERATING LIFE TESTS

No.	CHARACTERISTICS	SYMBOL	CONDITIONS	UNIT
1	Ambient Temperature	T_{amb}	+ 25 ± 3	°C
2	Collector-Base Voltage	V_{CB}	- 45	V
3	Power Dissipation 1	P_{tot1}	Maximum rating at T_{amb} according to derating curve (Note 1)	W

NOTES


1. See Item 5 of Table 1(b) and Figure 1.

FIGURE 5(a) - ELECTRICAL CIRCUIT FOR HIGH TEMPERATURE REVERSE BIAS BURN-IN

Not applicable.

FIGURE 5(b) - ELECTRICAL CIRCUIT FOR POWER BURN-IN AND OPERATING LIFE TESTS

Not applicable.

	<p style="text-align: center;">ESA/SCC Detail Specification No. 5207/005</p>	<p>PAGE 18 ISSUE 6</p>
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4.8 ENVIRONMENTAL AND ENDURANCE TESTS (CHARTS IV AND V OF ESA/SCC GENERIC SPECIFICATION NO. 5000)

4.8.1 Electrical Measurements on Completion of Environmental Tests

The parameters to be measured on completion of environmental tests are scheduled in Table 2. Unless otherwise stated, the measurements shall be performed at $T_{amb} = +22 \pm 3$ °C.

4.8.2 Electrical Measurements at Intermediate Points and on Completion of Endurance Tests

The parameters to be measured at intermediate points and on completion of endurance testing are scheduled in Table 6 of this specification. Unless otherwise stated, the measurements shall be performed at $T_{amb} = +22 \pm 3$ °C.

4.8.3 Conditions for Operating Life Tests (Part of Endurance Testing)

The requirements for operating life testing are specified in Section 9 of ESA/SCC Generic Specification No. 5000. The conditions for operating life testing shall be the same as specified in Table 5(b) for the power burn-in test.

4.8.4 Electrical Circuits for Operating Life Tests

The circuit to be used for performance of the operating life tests shall be the same as shown in Figure 5(b) for power burn-in.

4.8.5 Conditions for High Temperature Storage Test (Part of Endurance Testing)

The requirements for the high temperature storage test are specified in ESA/SCC Generic Specification No. 5000. The temperature to be applied shall be the maximum storage temperature specified in Table 1(b) of this specification.



TABLE 6 - ELECTRICAL MEASUREMENTS AT INTERMEDIATE POINTS AND ON COMPLETION OF ENDURANCE TESTING

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN.	MAX.	
4	Collector-Base Cut-off Current	I_{CBO}	As per Table 2	As per Table 2	-	-20	nA
6	D.C. Forward Current Transfer Ratio	h_{FE2}	As per Table 2	As per Table 2 Variants 01, 02, 05, 07, 09 Variants 03, 04, 06, 08, 10	150 300	450 900	-
7	Collector-Emitter Saturation Voltage	$V_{CE(SAT)2}$	As per Table 2	As per Table 2	-	-0.25	V
9	D.C. Forward Current Transfer Ratio Comparison	$\frac{h_{FE2-1}}{h_{FE2-2}}$	As per Table 2	As per Table 2	0.85	1.18	-
10	Base-Emitter Voltage Differential	$ V_{BE1} - V_{BE2} $	As per Table 2	$V_{CE} = 5.0V$ $I_C = 100\mu A$ (Note 1)	-	6.0	mV
10(a)	Base-Emitter Voltage Differential Change	$ \Delta(V_{BE1} - V_{BE2}) $ ΔT_{amb}	As per Table 3	As per Table 3 (Note 1)	-	1.0	mV
				As per Table 3 (Note 1)	-	1.2	

NOTES

1. To be measured once, at completion of endurance tests.